NSN 5961-01-519-0873

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-519-0873 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.119 inches **Overall Height:** Between 0.034 inches and 0.040 inches **Overall Width:** Between 0.083 inches and 0.104 inches **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-23 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.00 reverse voltage, dc **Current Rating Per Characteristic:** 12.00 amperes all primaries **Power Rating Per Characteristic:** 300.0 watts forward power dissipation, dc pascal **Capacitance Rating In Picofarads:** 120.0 **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0